

HL7301MG/02MG

InGaAsP Laser Diode

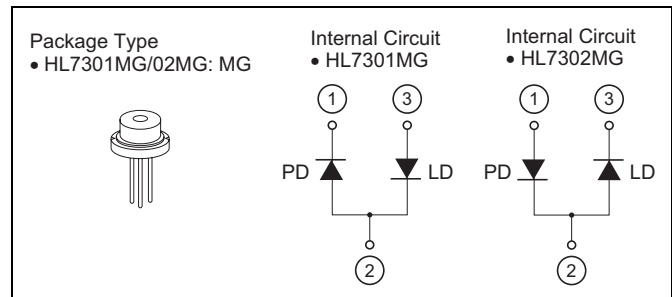
ODE2004-00 (P)
Preliminary
Rev.0
Jun. 23, 2008

Description

The HL7301MG/02MG are 0.73 μm band InGaAsP laser diode with a multi-quantum well(MQW) structure. It is suitable as a light source for medical sensor applications and various other types of optical equipment.

Features

- Infrared light output: $\lambda_p = 730\text{nm}$ Typ ($P_o=40\text{mW}$)
- Optical output power: 40mW
- Low operating current: 75mA Typ ($P_o=40\text{mW}$)
- Built-in monitor photodiode
- Single longitudinal mode



Absolute Maximum Ratings

($T_c = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Optical output power	P_o	50	mW
LD reverse voltage	$V_{R(LD)}$	2	V
PD reverse voltage	$V_{R(PD)}$	30	V
Operating temperature	T_{opr}	-10 to +60	$^\circ\text{C}$
Storage temperature	T_{stg}	-40 to +85	$^\circ\text{C}$

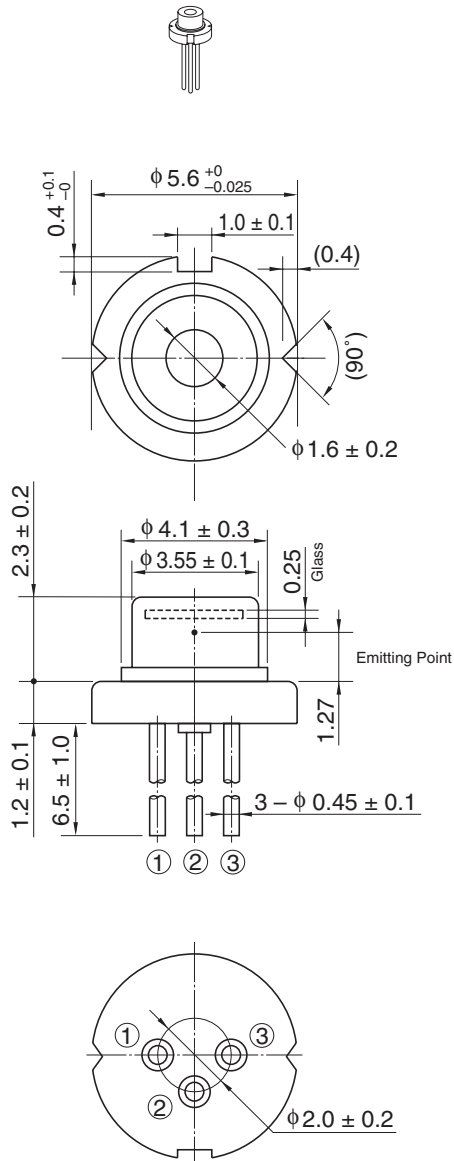
Optical and Electrical Characteristics

($T_c = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Threshold current	I_{th}	—	30	60	mA	—
Slope efficiency	η_s	0.7	0.9	1.4	mW/mA	$24 \text{ (mW)} / (I_{(32\text{mW})} - I_{(8\text{mW})})$
Operating current	I_{OP}	—	75	100	mA	$P_o = 40 \text{ mW}$
Operating voltage	V_{OP}	—	2.5	—	V	$P_o = 40 \text{ mW}$
Lasing wavelength	λ_p	720	730	740	nm	$P_o = 40 \text{ mW}$
Beam divergence parallel to the junction	$\theta_{//}$	7	9	14	$^\circ$	$P_o = 40 \text{ mW}$, FWHM
Beam divergence perpendicular to the junction	θ_{\perp}	14	18	25	$^\circ$	$P_o = 40 \text{ mW}$, FWHM
Monitor current	I_s	0.15	0.30	0.60	mA	$P_o = 40 \text{ mW}$, $V_{R(PD)} = 5 \text{ V}$

Package Dimensions

As of July, 2002
Unit: mm



OPJ Code	LD/MG
JEDEC	—
JEITA	—
Mass (reference value)	0.3 g

Cautions

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1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.
When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.
3. Definition of items shown in this CAS is in accordance with that shown in Opto Device Databook issued by OPJ unless otherwise specified.

Sales Offices



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